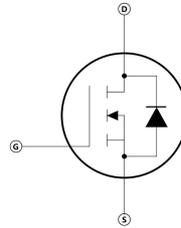


Features

- Low gate charge
- Low Crss (typical 13pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

Applications

- High efficiency switch mode power supplies
- Electronic lamp ballasts based on half bridge
- LED power supplies



Absolute Ratings (Tc=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	1000	V	
Drain Current -continuous	I _D	T _C =25°C	10	A
		T _C =100°C	6.0*	A
Drain Current - pulse (note 1)	I _{DM}	36	A	
Gate-Source Voltage	V _{GSS}	±30	V	
Single Pulsed Avalanche Energy (note 2)	E _{AS}	858	mJ	
Avalanche Current (note 1)	I _{AR}	10	A	
Repetitive Avalanche Current (note 1)	E _{AR}	27.7	mJ	
Peak Diode Recovery dv/dt (note 3)	dv/dt	4.1	V/ns	
Power Dissipation(TO-247/TO-263)	P _D	186.5	W	
Power Dissipation(TO-220F)		67.9	W	
Operating and Storage Temperature Range	T _J ,T _{STG}	-55~+150	°C	
Maximum Lead Temperature for Soldering Purposes	T _L	300	°C	

Electrical Characteristics($T_{CASE}=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Tests conditions	Min	Typ	Max	Units
Off-Characteristics						
Drain-Source Voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$	1000	-	-	V
Breakdown Voltage	$\Delta BV_{DSS}/\Delta T_J$	$I_D=250\mu A$,referenced to $25^{\circ}C$	-	0.98	-	$V/^{\circ}C$
Temperature Coefficient		$V_{DS}=900V, V_{GS}=0V, T_C=25^{\circ}C$	-	-	1	μA
Zero Gate Voltage Drain Current		$V_{DS}=720V, T_C=125^{\circ}C$	-	-	10	μA
Gate-body leakage current, forward	I_{GSSF}	$V_{DS}=0V, V_{GS}=30V$	-	-	100	nA
Gate-body leakage current,reverse	I_{GSSR}	$V_{DS}=0V, V_{GS}=30V$	-	-	-100	nA
On-Characteristics						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2.25	3.3	4.40	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=1A, 25^{\circ}C$	-	1.45	1.95	Ω
Forward Transconductance	g_{fs}	$V_{DS}=40V, I_D=4.5A$ (note 4)	-	9.5	-	S
Dynamic Characteristics						
Gate resistance	R_g	F=1.0MHz open drain	0.5	-	3	Ω
Input capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V, F=1.0MHz$	1200	2150	2830	pF
Output capacitance	C_{oss}		100	189	246	pF
Reverse transfer capacitance	C_{rss}		5	13	17	pF
Switching Characteristics						
Turn-On delay time	$t_{d(on)}$	$V_{DD}=450V, I_D=9A, R_G=25\Omega$ (note 4,5)	-	53	121	ns
Turn-On rise time	t_r		-	116	235	ns
Turn-Off delay time	$t_{d(off)}$		-	97	199	ns
Turn-Off Fall time	t_f		-	69	171	ns
Total Gate Charge	Q_g	$V_{DS}=720V, I_D=9A, V_{GS}=10V$ (note4,5)	-	43	56	nC
Gate-Source charge	Q_{gs}		-	15	40	nC
Gate-Drain charge	Q_{gd}		-	21	50	nC
Drain-Source Diode Characteristics and Maximum Ratings						
Maximum Continuous Drain -Source Diode		I_s	-	-	10	A

Forward Current						
Maximum Pulsed Drain-Source Diode Forward Current		I_{SM}	-	-	36	A
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=1A$	-	0.72	1.2	V
Reverse recovery time	t_{rr}	$V_{GS}=0V, I_S=9A$ $di_F/dt=100A/us$ (note 4)	-	539	1200	ns
Reverse recovery charge	Q_{rr}		-	6.41	12	uC

Parameter	Symbol	Value		Unit
		TO-247/TO-263/ TO-220C	TO-220F	
Thermal Resistance, Junction to Case	$R_{th(j-c)}$	0.67	1.84	°C/W
Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	40	62.5	°C/W

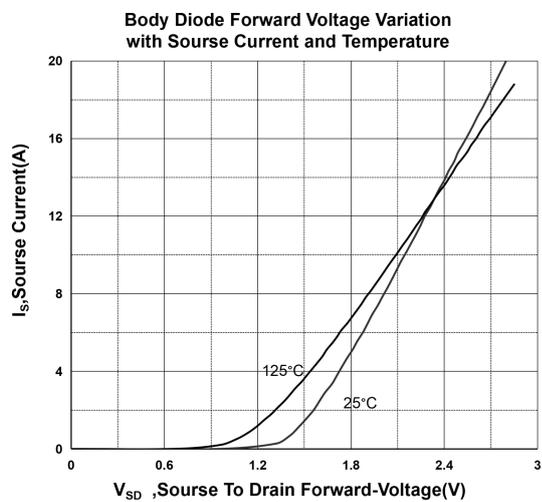
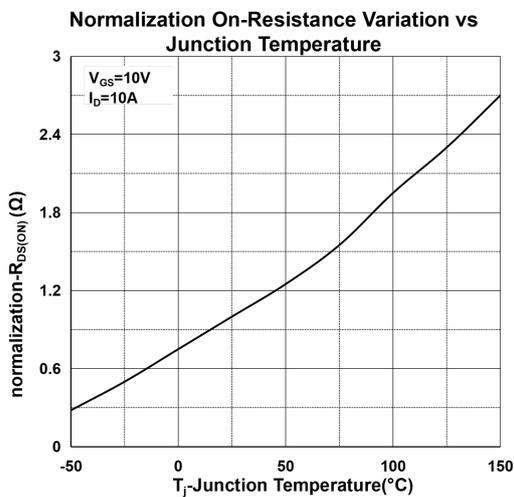
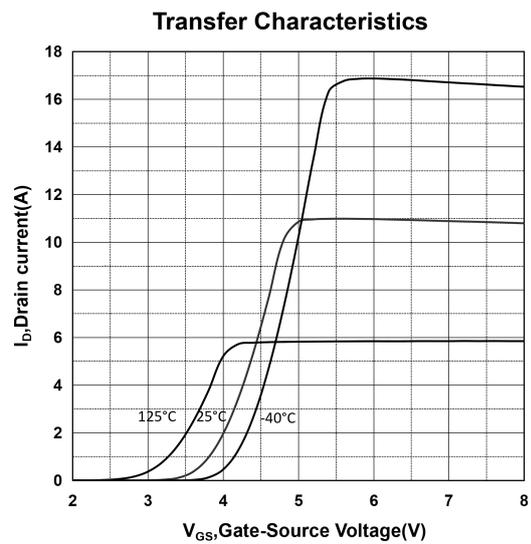
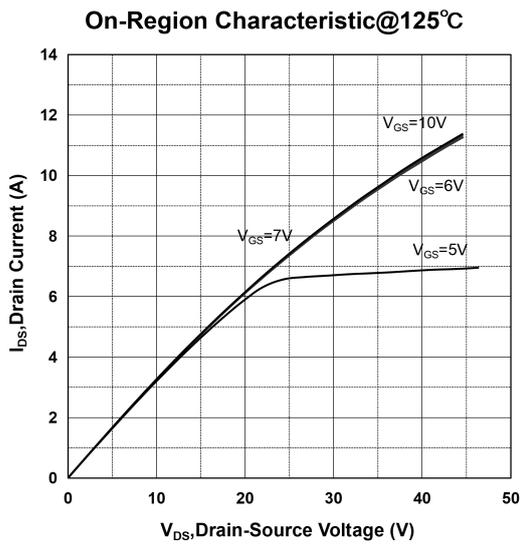
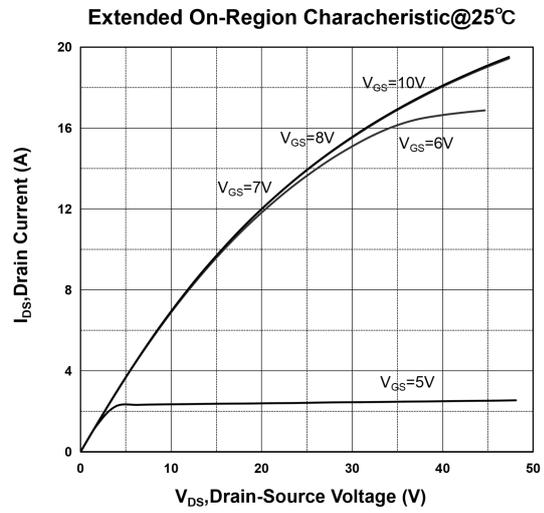
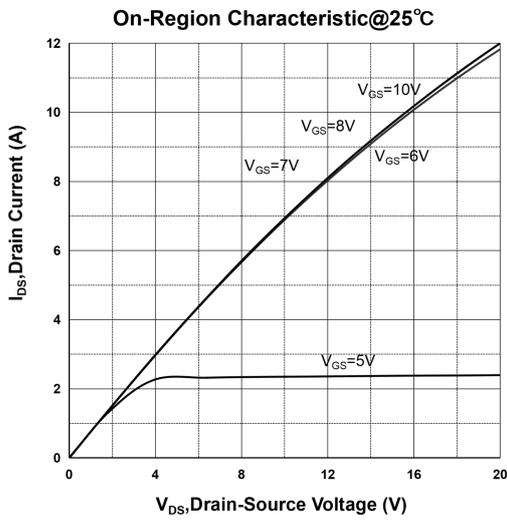
Notes:

- 1:Pulse width limited by maximum junction temperature
- 2:L=20mH, $I_{AS}=10A, V_{DD}=50V, R_G=25\Omega$, Starting $T_J=25^\circ C$
- 3: $I_{SD}\leq 10A, di/dt\leq 200A/us, V_{DD}\leq BV_{DSS}$, Starting $T_J=25^\circ C$
- 4:Pulse Test:Pulse Width $\leq 200us$,Duty Cycle $\leq 2\%$
- 5:Essentially independent of operating temperature

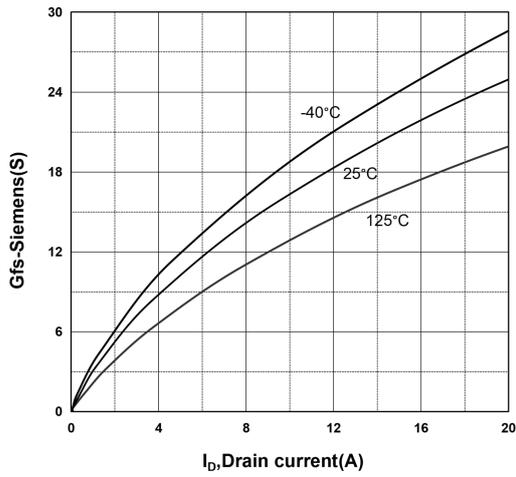
Order information

Order codes	Package	Packaging
MS10N100HGC0	TO-247	Tube
MS10N100HGT1	TO-220F	Tube
MS10N100HGE0	TO-263	Tube
MS10N100HGT0	TO-220	Tube

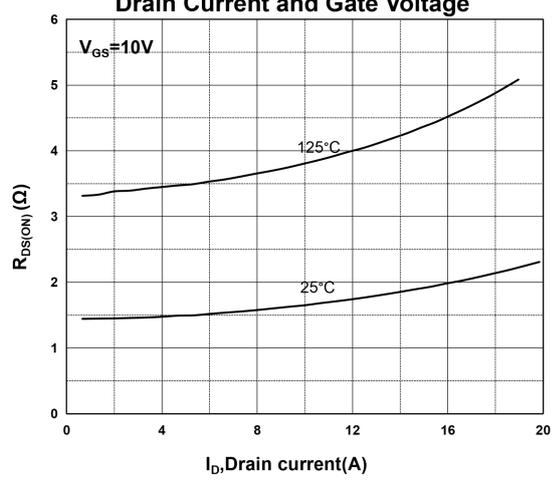
Electrical Characteristics



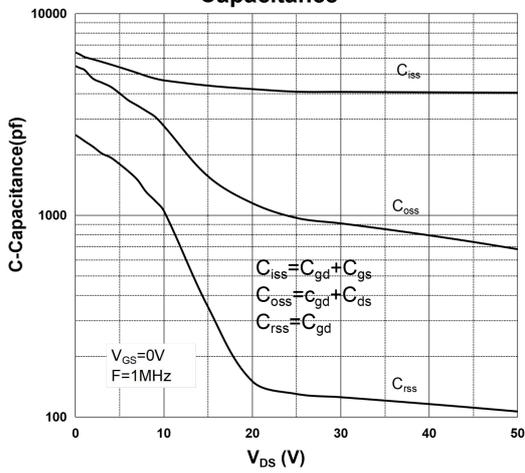
Transconductance



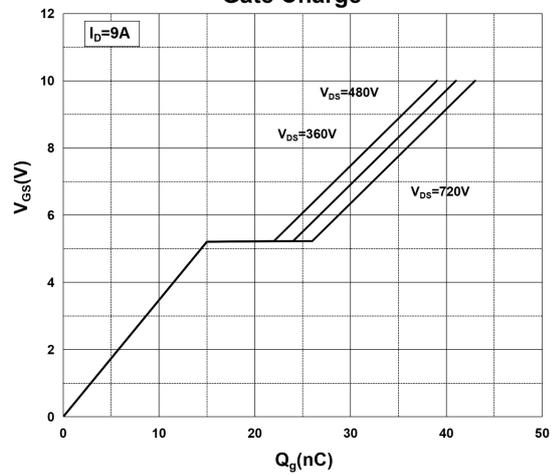
On-Resistance Variation vs Drain Current and Gate Voltage



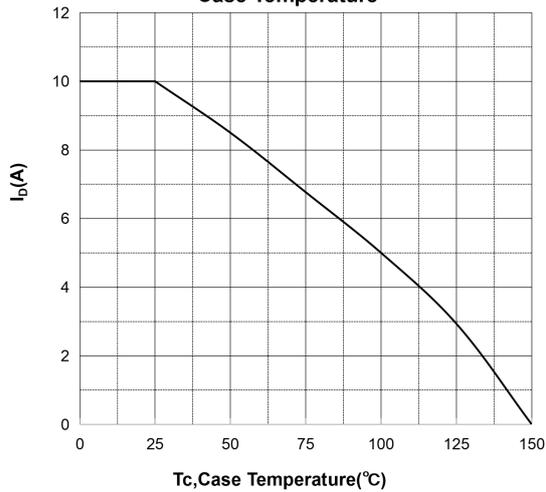
Capacitance



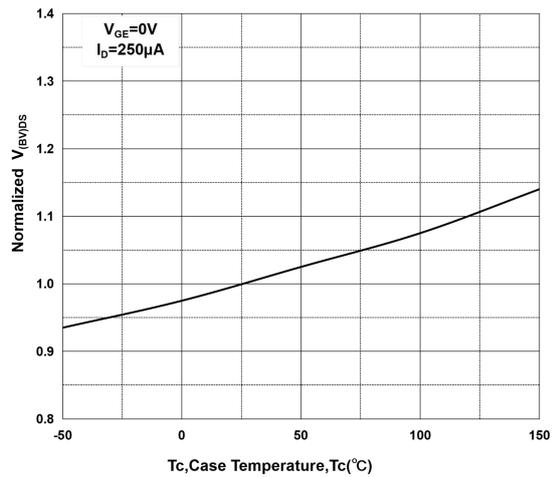
Gate Charge



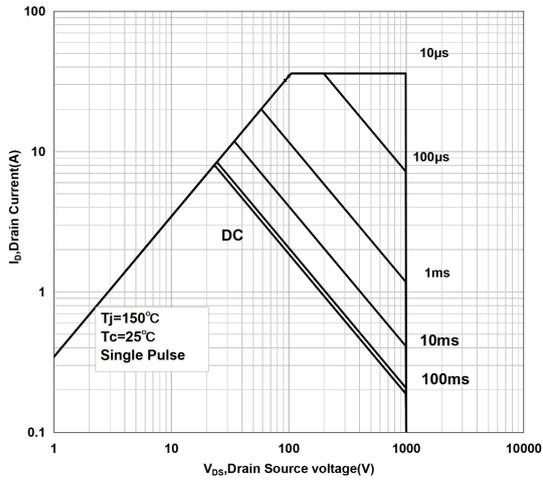
Maximum Drain Current vs Case Temperature



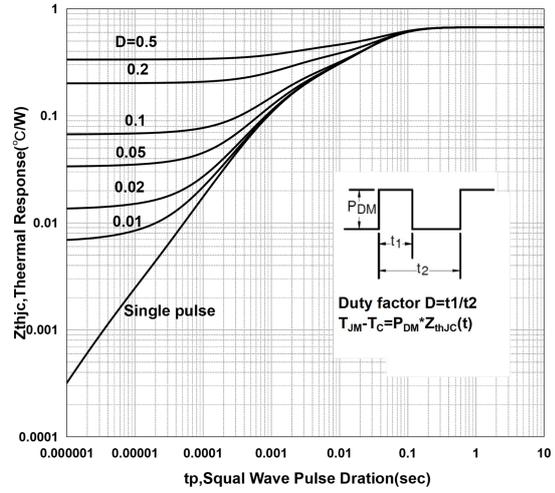
Normalized $V_{(BV)DS}$ vs temperature



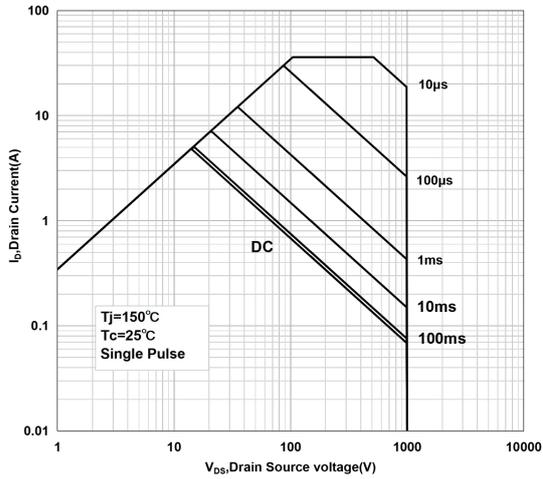
Safe Operating Area for TO-247/TO-263/TO-220C



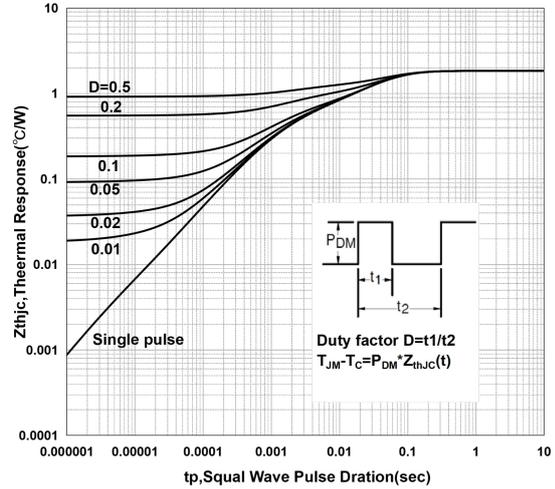
Transient response Curve for TO-247/TO-263/TO-220C



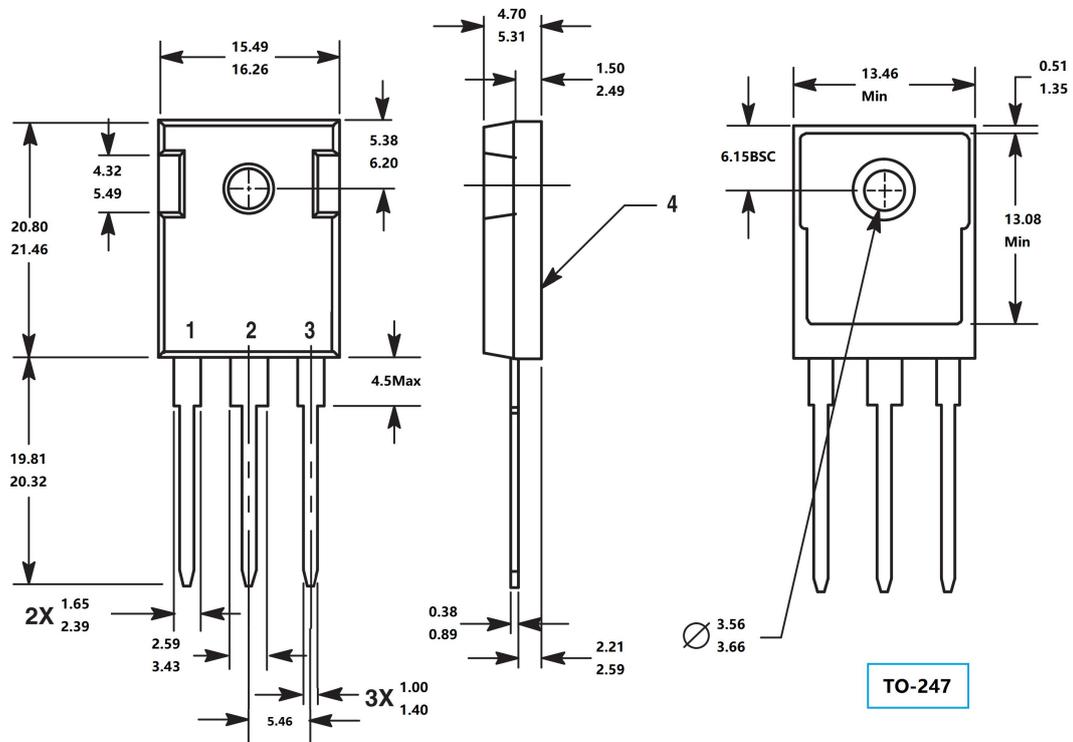
Safe Operating Area for TO-220F

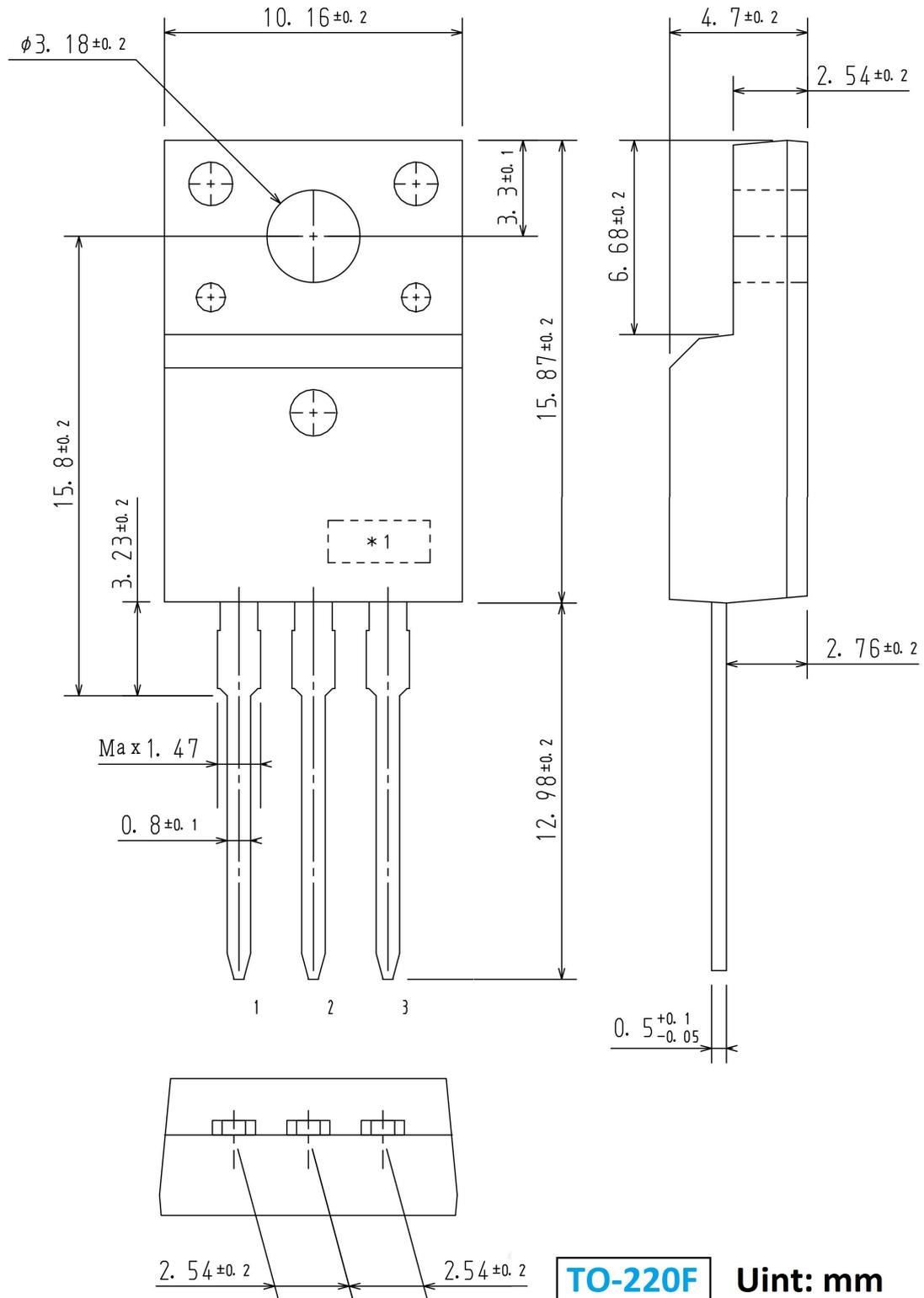


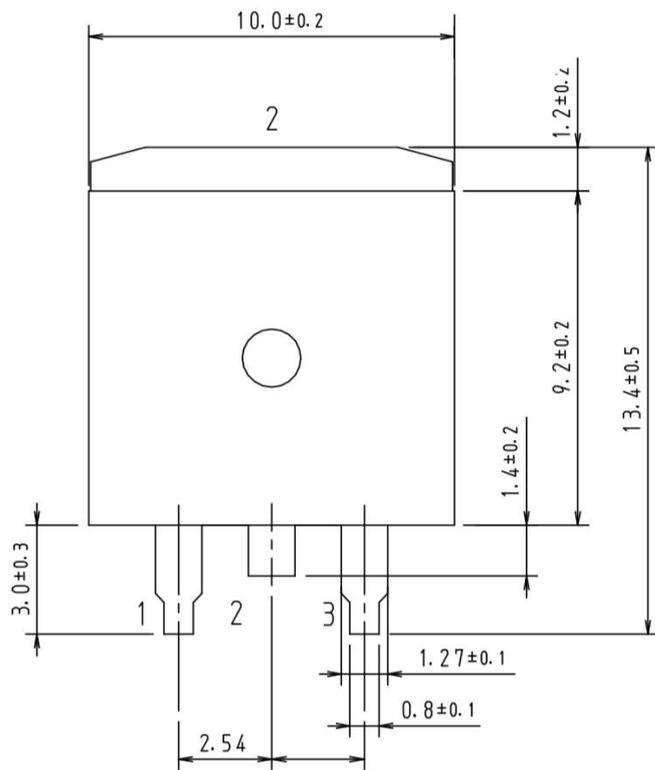
Transient response Curve for TO-220F



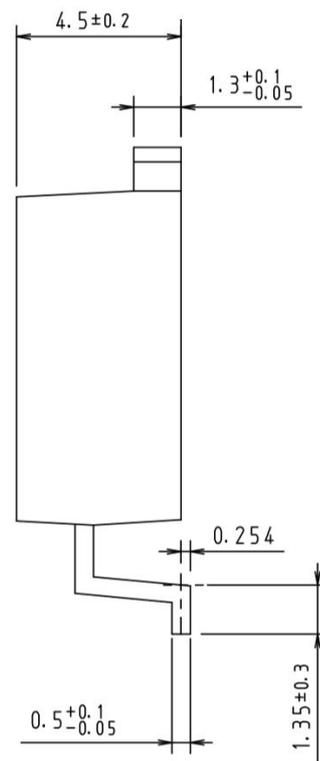
Package Mechanical DATA







TO-263



Unit:mm

